



Docket No.: 474082002600
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Nobumitsu TAKASE et al.

Application No.: 10/828,555

Confirmation No.: 5435

Filed: April 21, 2004

Art Unit: 1722

For: MANUFACTURING METHOD OF HIGH
RESISTIVITY SILICON SINGLE CRYSTAL

Examiner: R. M. Kunemund

AMENDMENT IN RESPONSE TO NON-FINAL OFFICE ACTION

MS Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

This is in response to the non-final Office Action dated May 17, 2006, for which a response was due on August 17, 2006. Filed herewith is a Petition and fee for a one-month(s) extension of time, thereby extending the deadline for response to September 18, 2006 (September 17, 2006 being a Sunday). Accordingly, this response is timely filed. Reconsideration and allowance of the pending claims, as amended, in light of the remarks presented herein are respectfully requested.

Remarks/Arguments begin on page 2 of this paper.